

Features

- High speed 10MBit/s
- High isolation voltage between input and output (Viso=5000 Vrms)
- Guaranteed performance from -40 ℃ to 85 ℃
- Wide operating temperature range of -55 °C to 100 °C
- Regulatory Approvals
 - UL UL1577 (E364000)
 - VDE EN60747-5-5(VDE0884-5)
 - CQC GB4943.1, GB8898
 - IEC60065, IEC60950

Applications

- Line receivers
- Telecommunication equipment

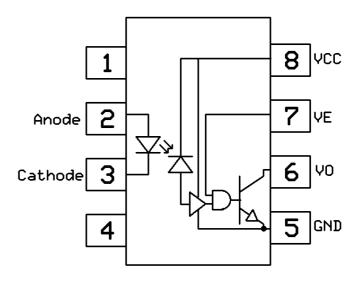
- Feedback loop in switch-mode power supplies
- Home appliances
- High speed logic ground isolation

Description

The CT2601 optocouplers consist of a 850 nm AlGaAS LED, optically coupled to a very high speed integrated photo-detector logic gate with a strobable output. This output features an open collector, there by permitting wired OR outputs. The switching parameters are guaranteed over the temperature range of -40 ℃ to +85 ℃. A maximum input signal of 5mA will provide a minimum output sink current of 13mA (fan out of 8).

Package Outline

Schematic



Note: Different lead forming options available. See package dimension.





Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings Units		Notes
Viso	Isolation voltage *1	5000	V _{RMS}	
Topr	Operating temperature	-55 ~ +85 °C		
Тѕтс	Storage temperature	-55 ~ +125	°C	
TsoL	Soldering temperature *2	260	°C	
Emitter				
lF	Forward current	50 mA		
V _R	Reverse voltage	5	V	
Pı	Power dissipation	100	mW	
Detector			<u>.</u>	
Po	Power dissipation	85 mW		
lo	Average Output current	50	mA	
Vo	Output voltage	7.0	V	1min(Max.)
Vcc	Supply voltage	7.0	V	
VE	Enable Input Voltage Not to Exceed VCC by more than 500mV	5.5	V	



Electrical Characteristics

 T_A = -40 - 85 °C (unless otherwise specified). Typical values are measured at T_A = 25°C and V_{CC} =5V

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	IF = 10mA	-	1.4	1.6	V	
VR	Reverse Voltage	IR = 10μA	5.0	-	-	V	
$\Delta V_F/\Delta T_A$	Temperature coefficient of forward voltage	IF =10mA	-	-1.8	-	mV/℃	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
Іссн	Logic High Supply Current	I _F =0mA, V _E =0.5V, V _{CC} =5.5V	-	6.5	10	mA	
Lance	Logic Low Supply		0.0	0.0	10	^	
ICCL	Current	I _F =10mA, V _E =0.5V, V _{CC} =5.5V	-	8.8	13	mA	
V _{EH}	High Level Enable Voltage	I _F =10mA, V _{CC} =5.5V	2.0	-	-	٧	
V _{EL}	Low Level Enable Voltage	I _F =10mA, V _{CC} =5.5V	-	-	0.8	V	
IEH	High Level Enable Current	V _E =0.5V, V _{CC} =5.5V	-	-0.53	-1.6	mA	
I _{EL}	Low Level Enable Current	V _E =2.0V, V _{CC} =5.5V	-	-0.75	-1.6	mA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
I	In a state of the second of the second	V _{CC} =5.5V, V _O =0.6V,		0.5	5	mA	
IFT	Input Threshold Current	V _E =2.0V, I _O =13mA	-	2.5			
	Lawia Llinda Outrout Comment	I _F =250μA, V _O =V _{CC} =5.5V,	- 2	0.0	100	μΑ	
Іон	Logic High Output Current	V _E =2.0V		2.0			
V	Law Lavel Output Valtage	I _F =5mA, V _{CC} =5.5V, V _E =2.0V,		0.05	0.0	V	
V _{OL}	V _{OL} Low Level Output Voltage I _O =13mA	-	0.35	0.6	v		



Electrical Characteristics

 T_A = -40 - 85 °C (unless otherwise specified). Typical values are measured at T_A = 25°C, V_{CC} =5V and I_F = 7.5mA

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
Т	Output Propagation Delay High			0.4	75		
T _{PHL}	To Low		-	34	75	ns	
Т	Output Propagation Delay Low to			39	75	ns	
T _{PLH}	High	C_L = 15pF, R_L = 350 Ω	-				
P _{WD}	Pulse Width Distortion		-	5	34	ns	
Tr	Output Rise Time		-	37	-	ns	
T _f	Output Fall Time		-	10	-	ns	
_	Enable Propagation Delay Low To	15	15				
TELH	High	VEH= 3.5V, C_L = 15pF, R_L =	-	15	-	ns	
Т	Enable Propagation Delay High	350Ω		15	5 -	ns	
T _{EHL}	To Low		-				
СМн	Common Mode Transient I _F = 0mA, V _{CM} = 50Vp-p, V _{OH} =	F000			1////		
CIVIH	Immunity at Logic High	$2.0V$, $R_L=350\Omega$	5000	_	-	V/µs	
CM.	Common Mode Transient	I _F =7.5mA, V _{CM} = 50Vp-p,	5000			V/µs	
CM∟	Immunity at Logic Low	$V_{OH}=0.8V$, $R_{L}=350\Omega$	5000	-			

80 85



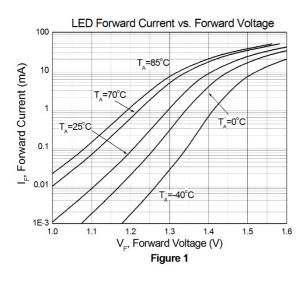
10MBit/s High Speed Logic Gate Optocoupler

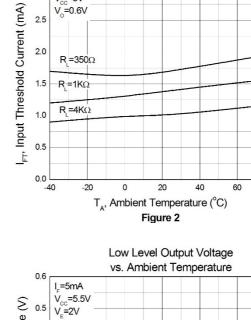
3.0

V__=5V

V_=0.6V

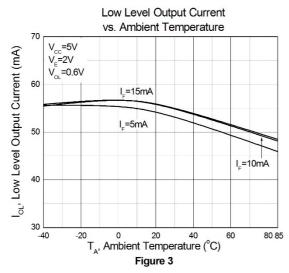
Typical Characteristic Curves

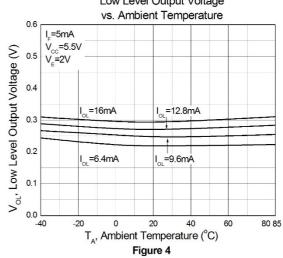




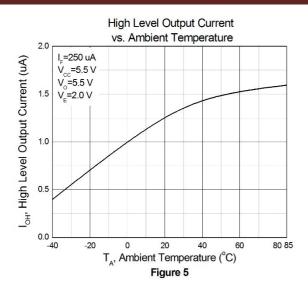
Input Threshold Current

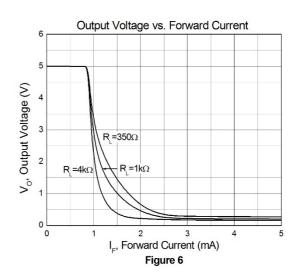
vs.Ambient Temperature

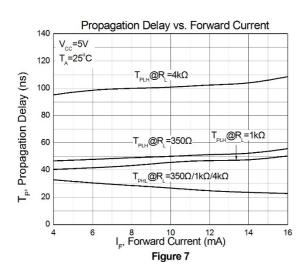


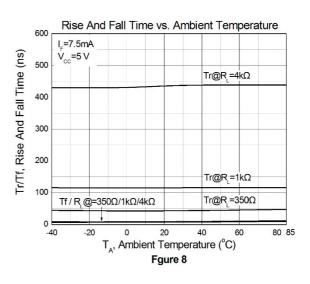


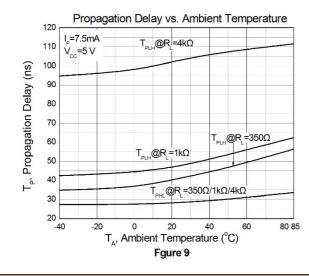


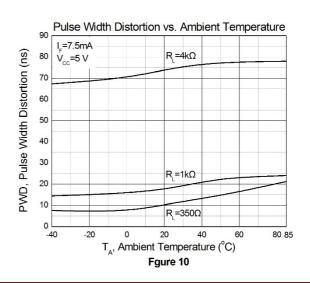




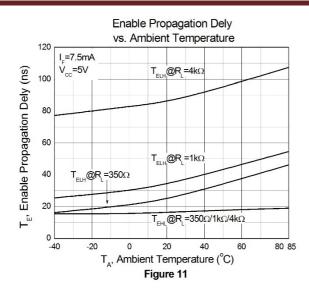




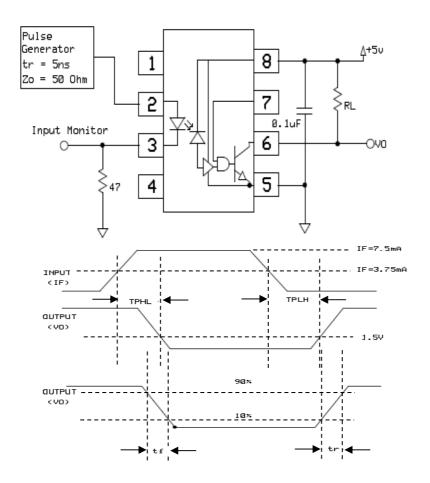






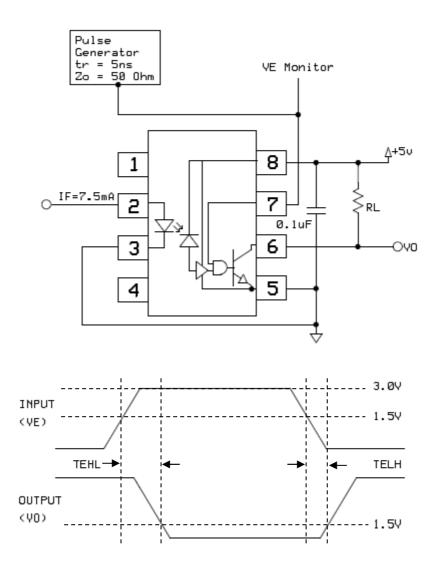


Test Circuits



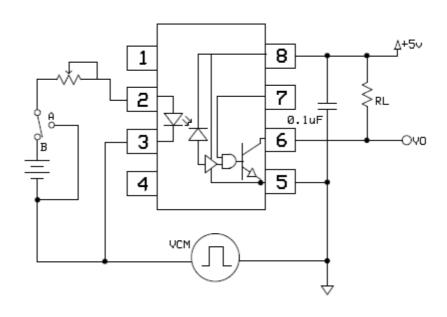
Switching Time Test Circuit

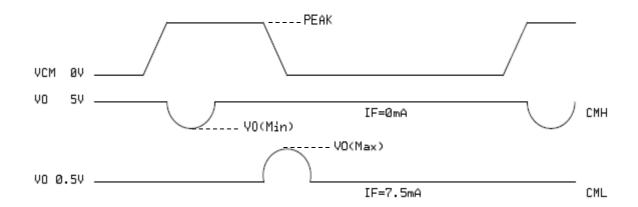




Enable Switching Time Test Circuit





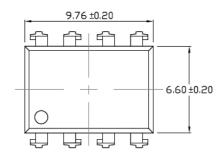


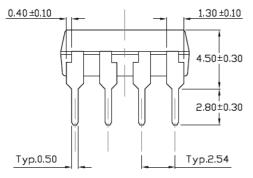
CMR Test Circuit

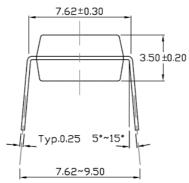


Package Dimension Dimensions in mm unless otherwise stated

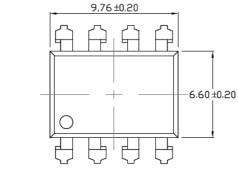
Standard DIP - Through Hole

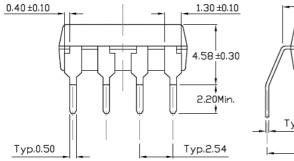






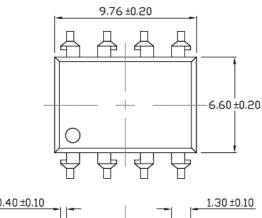
Gullwing (400mil) Lead Forming – Through Hole (M Type)

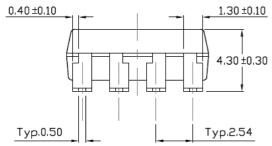


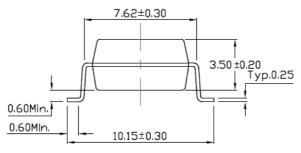




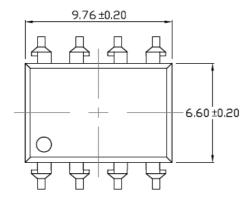
Surface Mount Lead Forming (S Type)

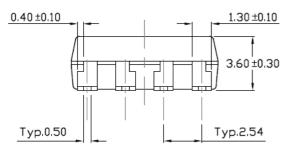


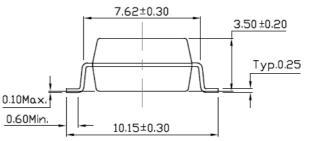




Surface Mount (Low Profile) Lead Forming (SL Type)

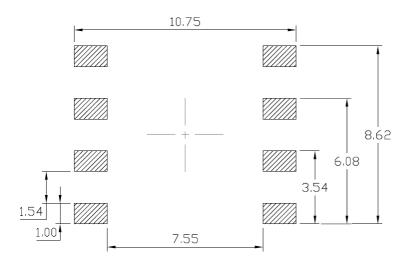




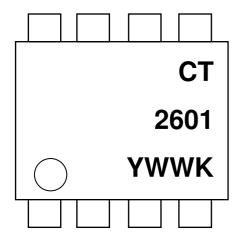




Recommended Solder Mask Dimensions in mm unless otherwise stated



Device Marking



Note:

CT : Denotes "CT Micro" 2601 : Product Number

Y : Fiscal Year WW : Work Week

K : Production Code



Ordering Information

CT2601Y(Z)

Y = Lead form option (S, SL, M or none)

Z = Tape and reel option (T1, T2 or none)

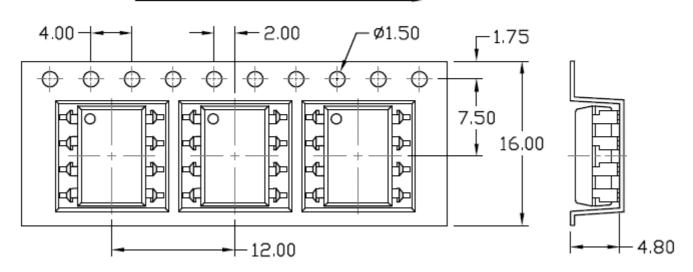
Option	Description	Quantity
None	Standard 8 Pin Dip	45 Units/Tube
М	Gullwing (400mil) Lead Forming	45 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1000 Units/Reel
SL(T1)	SL(T1) Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	
SL(T2) Surface Mount (Low Profile) Lead Forming–With Option 2 Taping 1000 Units		1000 Units/Reel



Carrier Tape Specifications Dimensions in mm unless otherwise stated

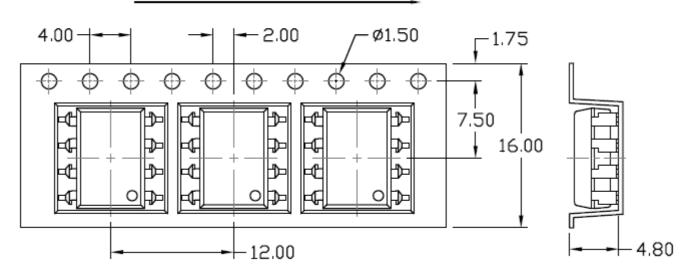
Option S(T1) & SL(T1)

Input Direction



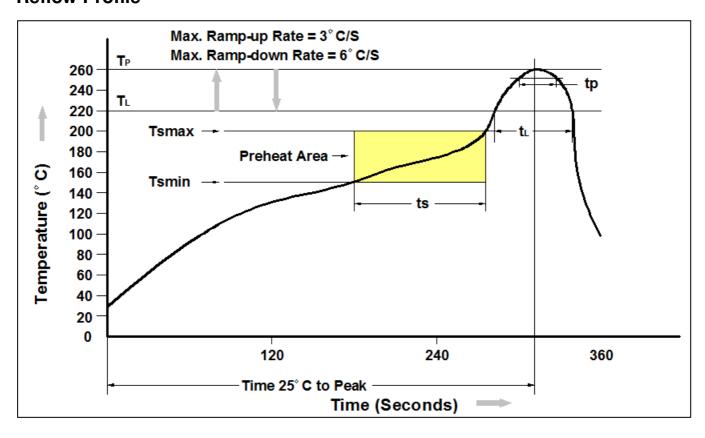
Option S(T2) & SL(T2)

Input Direction





Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150℃
Temperature Max. (Tsmax)	200℃
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t _L to t _P)	3 ℃/second max.
Liquidous Temperature (TL)	217℃
Time (t _L) Maintained Above (T _L)	60 - 150 seconds
Peak Body Package Temperature	260℃ +0℃ / -5℃
Time (t _P) within 5 °C of 260 °C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25 ℃ to Peak Temperature	8 minutes max.





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